

2SK435

Silicon N-Channel Junction FET

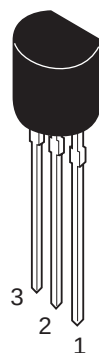
REJ03G0812-0200
(Previous ADE-208-1171)
Rev.2.00
Aug.10.2005

Application

Low frequency / High frequency amplifier

Outline

RENESAS Package code: PRSS0003DB-C
(Package name: TO-92 (2))



- 1. Drain
- 2. Source
- 3. Gate

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DS}	22	V
Gate to source voltage	V_{GS0}	-22	V
Drain current	I_D	100	mA
Gate current	I_G	10	mA
Channel power dissipation	Pch	300	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Electrical Characteristics

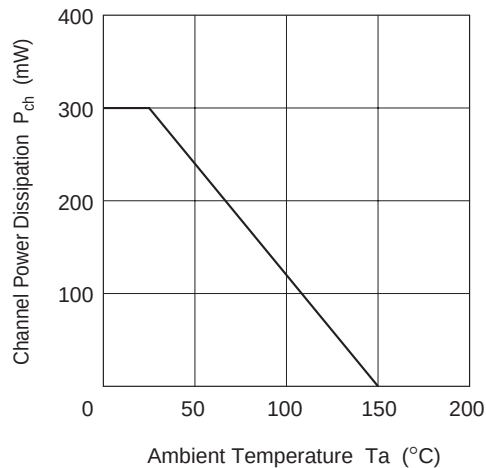
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Gate to source breakdown voltage	$V_{(BR)GSS}$	-22	—	—	V	$I_G = -10 \mu A$, $V_{DS} = 0$
Gate cutoff current	I_{GSS}	—	—	-10	nA	$V_{GS} = -15 V$, $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	—	—	-2.5	V	$V_{DS} = 5 V$, $I_D = 10 \mu A$
Drain current	I_{DSS}^{*1}	12	—	30	mA	$V_{DS} = 5 V$, $V_{GS} = 0$, Pulse test
Forward transfer admittance	$ y_{fs} $	20	—	—	mS	$V_{DS} = 5 V$, $I_D = 10 mA$, $f = 1 kHz$
Input capacitance	Ciss	—	9.0	11.0	pF	$V_{DS} = 5 V$, $V_{GS} = 0$, $f = 1 MHz$
Reverse transfer capacitance	Crss	—	2.8	4.0	pF	$V_{DS} = 5 V$, $V_{GS} = 0$, $f = 1 MHz$
Noise figure	NF	—	0.5	3.0	dB	$V_{DS} = 5 V$, $I_D = 1 mA$, $f = 1 kHz$, $R_g = 1 k\Omega$

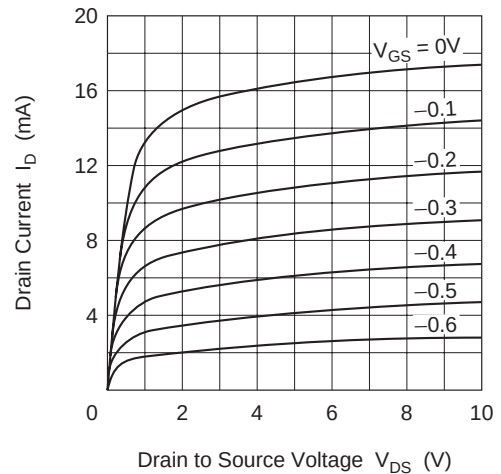
Note: 1. The 2SK435 is grouped by I_{DSS} as follows.

Grade	C	D
I_{DSS}	12 to 22	18 to 30

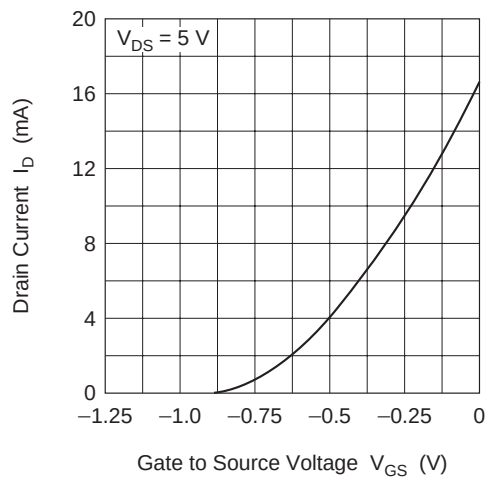
Maximum Channel Dissipation Curve



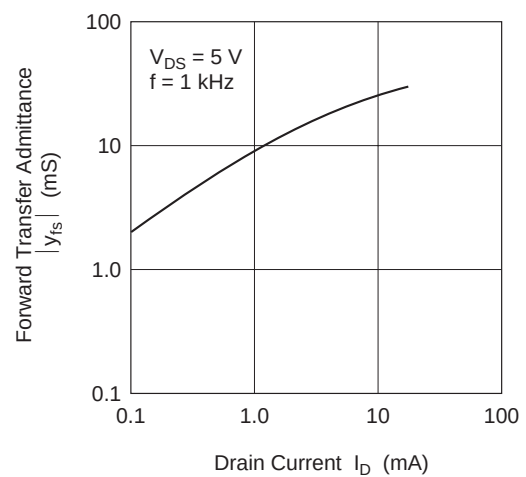
Typical Output Characteristics



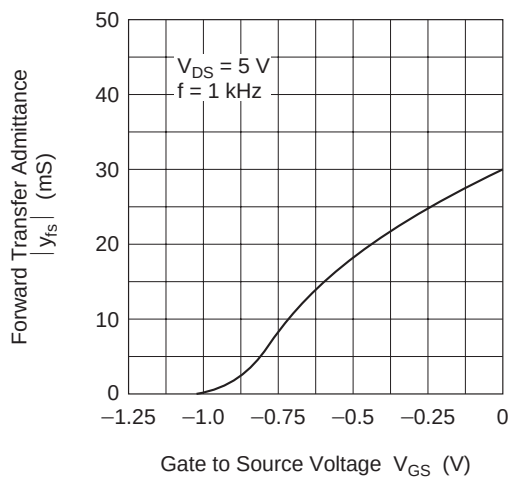
Typical Transfer Characteristics



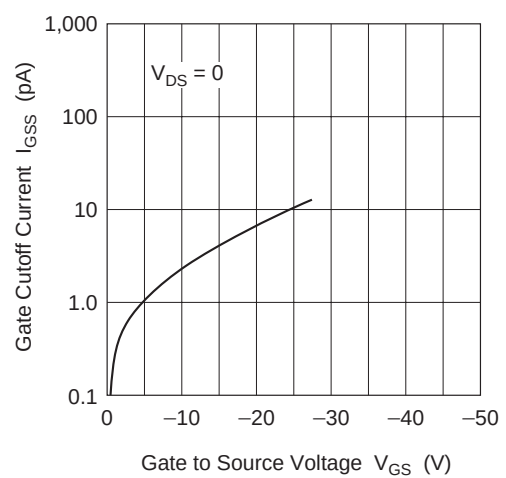
Forward Transfer Admittance vs. Drain Current

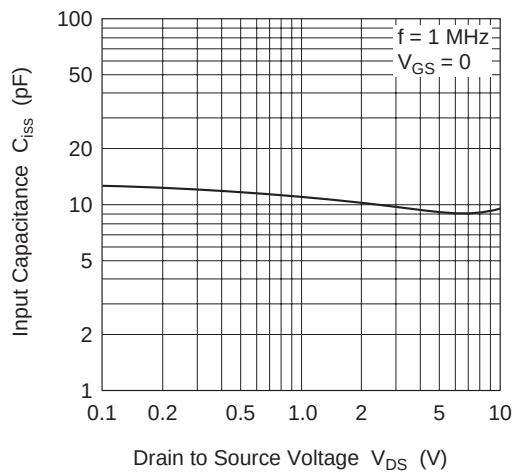
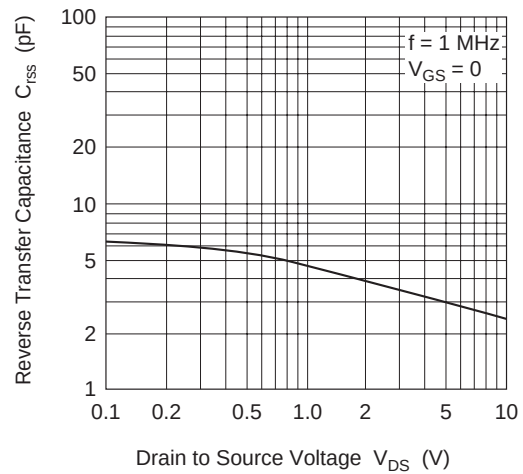
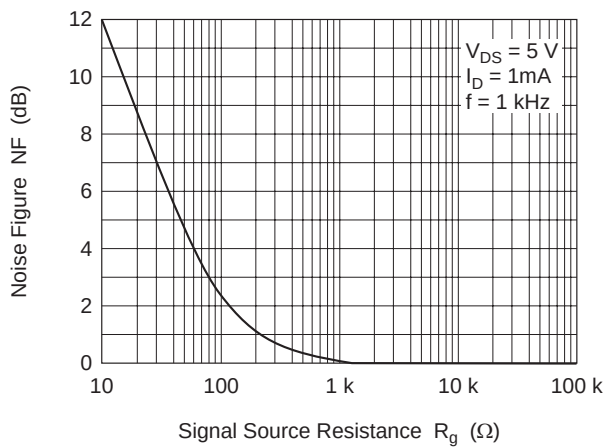


Forward Transfer Admittance vs. Gate to Source Voltage

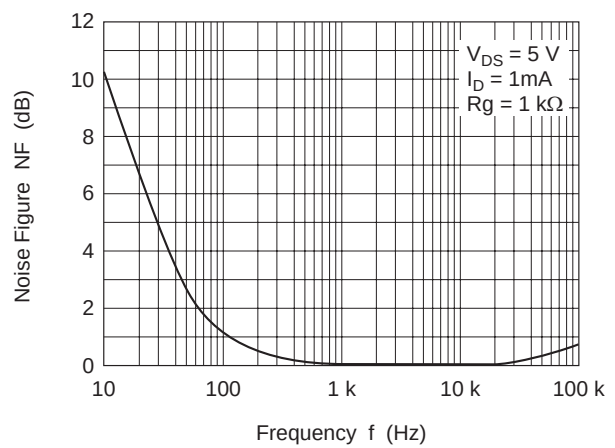


Gate Cutoff Current vs. Gate to Source Voltage

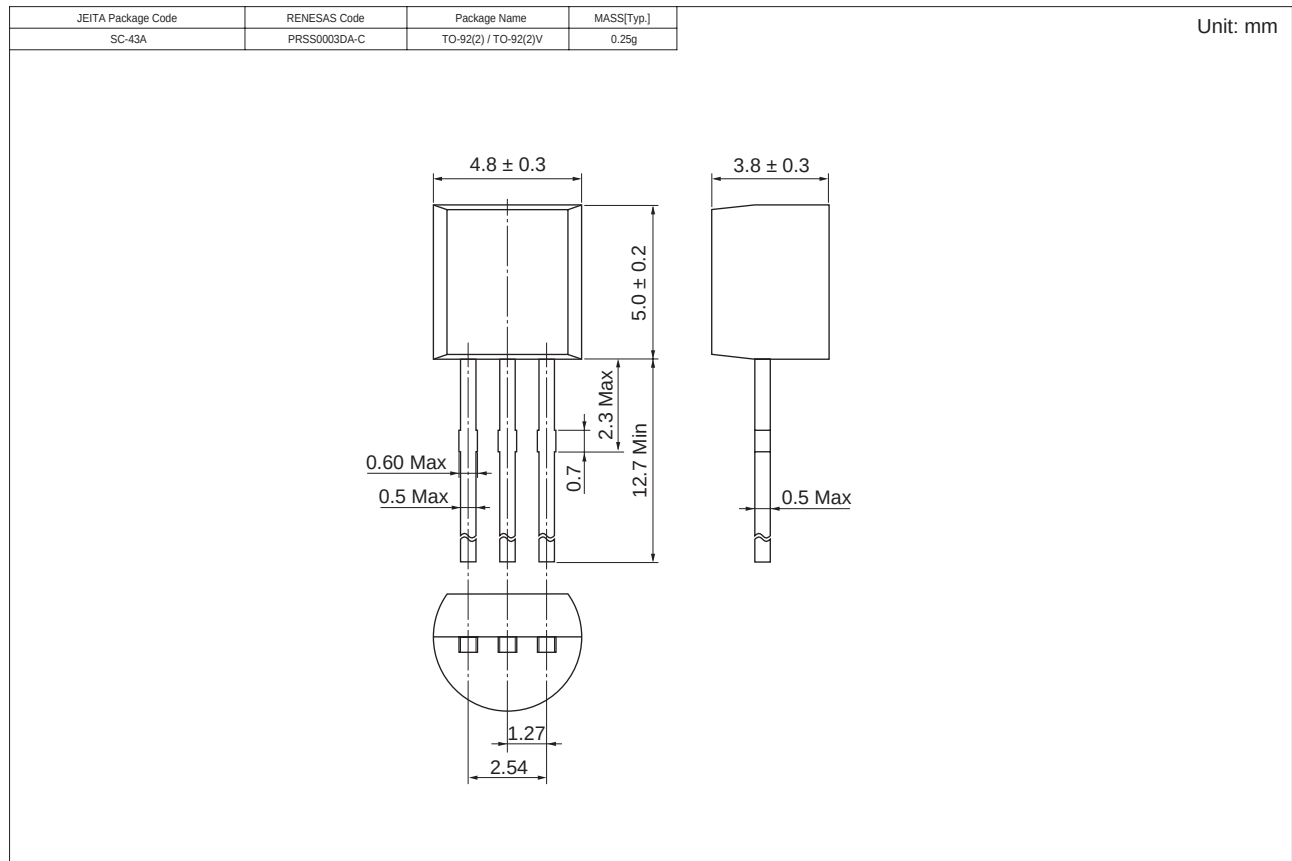


Input Capacitance vs.
Drain to Source VoltageReverse Transfer Capacitance
vs. Drain to Source VoltageNoise Figure vs.
Signal Source Resistance

Noise Figure vs. Frequency



Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK435CTZ	2500	Radial taping, Hold box
2SK435DTZ	2500	Radial taping, Hold box

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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